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April 2014

## **FXL2T245**

# Low-Voltage, Dual-Supply, 2-Bit, Signal Translator with Configurable Voltage Supplies and Signal Levels and 3-State Outputs

## **Features**

- Bi-Directional Interface between any 2 Levels from 1.1 V to 3.6 V
- Fully Configurable, Inputs Track V<sub>CC</sub> Level
- Non-Preferential Power-up Sequencing; either V<sub>CC</sub> maybe Powered-up First
- Outputs Remain in 3-State until Active V<sub>CC</sub> Level is Reached
- Outputs Switch to 3-State if either V<sub>CC</sub> is at GND
- Power-Off Protection
- Control Inputs (T/R, OE) Levels are Referenced to V<sub>CCA</sub> Voltage
- Packaged in 10-Lead MicroPak
   (1.6 mm x 2.1 mm) Package
- ESD Protection Exceeds:
  - 4 kV HBM ESD JESD22-A114 & Mil Std 883e 3015.7)
  - 8kV HBM I/O to GND ESD (per JESD22-A114 & Mil Std 883e 3015.7)
  - 1 kV CDM ESD (per ESD STM 5.3)
  - 200 V MM ESD (per JESD22-A115 & ESD STM5.2)

## **Description**

The FXL2T245 is a configurable, dual-voltage-supply translator designed for uni-directional and bi-directional voltage translation between two logic levels. The device allows translation between voltages as high as 3.6 V to as low as 1.1 V. The A port tracks the  $V_{\rm CCA}$  level and the B port tracks the  $V_{\rm CCB}$  level. This allows for bi-directional voltage translation over a variety of voltage levels: 1.2 V, 1.5 V, 1.8 V, 2.5 V, and 3.3 V.

The device remains in 3-state until both  $V_{\rm CC}s$  reach active levels, allowing either  $V_{\rm CC}$  to be powered-up first. Internal power-down control circuits place the device in 3-state if either  $V_{\rm CC}$  is removed.

The Transmit / Receive  $(T/\overline{R})$  input determines the direction of data flow through the device. The  $\overline{OE}$  input, when HIGH, disables both the A and B ports by placing them in a 3-state condition. The FXL2T245 is designed so control pins  $T/\overline{R}$  and  $\overline{OE}$  are supplied by  $V_{CCA}$ .

## **Ordering Information**

Part Number	Operating Temperature Range	Package	Packing Method
FXL2T245L10X	-40°C to +85°C	10-Lead, MicroPak™, JEDEC MO255,1.6 x 2.1 mm	Tape and Reel

# **Pin Configuration**

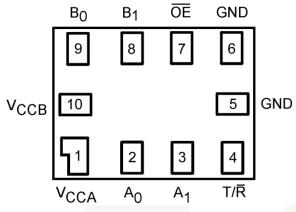


Figure 1. Pin Assignments

## **Pin Descriptions**

Pin#	Pin Name	Description
1	V <sub>CCA</sub>	Side A Power Supply
2	<b>A</b> <sub>0</sub>	Side A Inputs or 3-State Outputs
3	A <sub>1</sub>	Side A Inputs or 3-State Outputs
4	T/R	Transmit/Receive Input
5, 6	GND	Ground
7	Ō/Ē	Output Enable Input
8	B <sub>1</sub>	Side B Inputs or 3- State Outputs
9	B <sub>0</sub>	Side B Inputs or 3-State Outputs
10	V <sub>CCB</sub>	Side B Power Supply

## **Truth Table**

Inp	outs	Outputs
ŌĒ	T/R	
LOW	LOW	Bus B Data to Bus A
LOW	HIGH	Bus A Data to Bus B

#### Notes:

- 1. LOW = low voltage level.
- 2. HIGH = high voltage level.

## **Functional Description**

## Power-Up / Power-Down Sequencing

Due to the chip design, the FXL2T245 translator offers the advantage of either  $V_{CC}$  being powered up first. When either  $V_{CC}$  is at 0 V, outputs are in a high-impedance state. The control inputs (T/R and  $\overline{OE}$ ) are designed to track the  $V_{CCA}$  supply. A pull-up resistor tying  $\overline{OE}$  to  $V_{CCA}$  should be used to ensure that bus contention, excessive currents, or oscillations do not occur during power-up/power-down. The size of the pull-up resistor is based upon the current-sinking capability of the  $\overline{OE}$  driver.

The recommended power-up sequence is:

- 1. Apply power to either  $V_{\text{CC}}$ .
- 2. Apply power to the T/R input (logic HIGH for A-to-B operation; logic LOW for B-to-A operation) and to the respective data inputs (A port or B port). This may occur at the same time as step 1.
- 3. Apply power to the other  $V_{CC}$ .
- 4. Drive the  $\overline{OE}$  input LOW to enable the device.

The recommended power-down sequence is:

- Drive OE input HIGH to disable the device.
- 2. Remove power from either V<sub>CC</sub>.
- 3. Remove power from the other V<sub>CC</sub>.

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Conditions	Min.	Max.	Unit		
V <sub>CCA</sub>	Cupply Voltage		-0.5	4.6	V		
V <sub>CCB</sub>	Supply Voltage			-0.5	4.6	V	
		I/O Port A		-0.5	4.6		
$V_{I}$	DC Input Voltage	I/O Port B		-0.5	4.6	V	
		Control Inputs (T/R, OE)		-0.5	4.6		
		Output 3-State		-0.5	4.6		
Vo	Output Voltage (3)	Output Active (An)	-0.5 to V <sub>CCA</sub>	0.5	٧		
	/*	Output Active (B <sub>n</sub> )		-0.5 to V <sub>CCB</sub>	0.5	i	
I <sub>IK</sub>	DC Input Diode Current	V <sub>I</sub> < 0 V			-50	mA	
1/	DC Output Diode Current	V <sub>0</sub> < 0 V		-50	mA		
I <sub>OK</sub>	DC Output Diode Current	Vo > Vcc		+50	IIIA		
I <sub>OH</sub> /I <sub>OL</sub>	DC Output Source/Sink Cu	rrent			±50	mA	
I <sub>CC</sub>	DC V <sub>CC</sub> or Ground Current	per Supply Pin			±100	mA	
$T_{STG}$	Storage Temperature Rang	e	•				
		Human Body Model,	All Pins		4		
ESD	Electrostatic Discharge	JESD22-A114, Mil Std 883e 3015.7	I/O to GND		8	kV	
LSD	Capability	Charged Device Model, JESD22-C10	1,STM 5.3		1		
		Machine Model, JESD22-A115,STM	5.2		200	V	

#### Note

## **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter		Conditions		Max.	Unit
V <sub>CC</sub>	Power Supply	Operating	V <sub>CCA</sub> or V <sub>CCB</sub>	1.1	3.6	٧
		Port A		0	3.6	
Vı	Input Voltage	Port B		0	3.6	V
		Control Inp	outs (T/R, OE)	0	V <sub>CCA</sub>	
			3.0 V to 3.6 V		±24	
			2.3 V to 2.7 V		±18	
I <sub>OH</sub> /I <sub>OL</sub>	Output Current	$V_{CC}$	1.65 V to 1.95 V		±6	mA
			1.40 V to 1.65 V		±2	
			1.1 V to 1.4 V		±0.5	
T <sub>A</sub>	Operating Temperature, Free Air			-40	+85	°C
ΔV/Δt	Minimum Input Edge Rate	V <sub>CCA/B</sub> =1.	1 V to 3.6 V		10	ns/V

#### Note:

4. All unused inputs must be held at V<sub>CCI</sub> or GND.

<sup>3.</sup> I/O absolute maximum ratings must be observed.

## **Electrical Characteristics**

Symbol	Parameter	Conditions	V <sub>cco</sub> (V)	V <sub>CCI</sub> (V)	Min.	Max.	Unit
				2.70 to 3.60	2.00		
				2.30 to 2.70	1.60		
		Data Inputs An, Bn		1.65 to 2.30	0.65 x V <sub>CCI</sub>		
				1.40 to 1.65	0.65 x V <sub>CCI</sub>		
	HIGH Level		1 10 10 0 00	1.10 to 1.40	0.90 x V <sub>CCI</sub>		V
V <sub>IH</sub>	Input <sup>(5)</sup>		1.10 to 3.60	2.70 to 3.60	2.00		\ \
				2.30 to 2.70	1.60		
		Control Pins /OE, T/R (Referenced to V <sub>CCA</sub> )		1.65 to 2.30	0.65 x V <sub>CCA</sub>		
		(Troforonoda to VCCA)		1.40 to 1.65	0.65 x V <sub>CCA</sub>		
				1.10 to 1.40	0.90 x V <sub>CCA</sub>		
	1	1		2.70 to 3.60		0.80	
				2.30 to 2.70		0.70	
		Data Inputs An, Bn		1.65 to 2.30		0.35 x V <sub>CCI</sub>	
				1.40 to 1.65	\	0.35 x V <sub>CCI</sub>	
V	LOW Level		1 10 to 2 60	1.10 to 1.40		0.10 x V <sub>CCI</sub>	V
V <sub>IL</sub>	Input <sup>(5)</sup>		1.10 to 3.60	2.70 to 3.60		0.80	
, A		Control Pins /OE, T/R (Referenced to V <sub>CCA</sub> )		2.30 to 2.70		0.70	
				1.65 to 2.30		0.35 x V <sub>CCI</sub>	
		(Herereneed to VCCA)		1.40 to 1.65		0.35 x V <sub>CCI</sub>	
l i				1.10 to 1.40		0.10 x V <sub>CCI</sub>	
		I <sub>OH</sub> = -100 μA	1.10 to 3.60	1.10 to 3.60	V <sub>CC0</sub> - 0.20		
		I <sub>OH</sub> = -12 mA	2.70	2.70	2.20		
		I <sub>OH</sub> = -18 mA	3.00	3.00	2.40		
	A.	$I_{OH} = -24 \text{ mA}$	3.00	3.00	2.20		
V	HIGH Level	$I_{OH} = -6 \text{ mA}$	2.30	2.30	2.00		V
V <sub>OH</sub>	Output <sup>(6)</sup>	I <sub>OH</sub> = -12 mA	2.30	2.30	1.80		]
		I <sub>OH</sub> = -18 mA	2.30	2.30	1.70	1	
		$I_{OH} = -6 \text{ mA}$	1.65	1.65	1.25		
- A		$I_{OH} = -2 \text{ mA}$	1.40	1.40	1.05		
	Y.	$I_{OH} = -0.5 \text{ mA}$	1.10	1.10	0.75 x V <sub>CC0</sub>		
		$I_{OL} = 100 \mu A$	1.10 to 3.60	1.10 to 3.60		0.20	
		$I_{OL} = 12 \text{ mA}$	2.70	2.70		0.40	
		$I_{OL} = 18 \text{ mA}$	3.00	3.00		0.40	
		I <sub>OL</sub> = 24 mA	3.00	3.00		0.55	
$V_{OL}$	LOW Level Output <sup>(6)</sup>	$I_{OL} = 12 \text{ mA}$	2.30	2.30		0.40	٧
	Calpat	I <sub>OL</sub> = 18 mA	2.30	2.30		0.60	
		I <sub>OL</sub> = 6 mA	1.65	1.65		0.30	
		I <sub>OL</sub> = 2 mA	1.40	1.40		0.35	
		I <sub>OL</sub> = 0.5 mA	1.10	1.10		0.30 x V <sub>CC0</sub>	

Continued on the following page...

## **Electrical Characteristics**

Symbol	Parameter	Conditions	V <sub>cco</sub> (V)	V <sub>CCI</sub> (V)	Min.	Max.	Unit
IL	Input Leakage Current, Control Pins	V <sub>I</sub> =V <sub>CCA</sub> or GND	3.60	1.10 to 3.60		±1.0	μА
lass	Power Off	$A_n$ , $V_1$ or $V_0$ =0 V to 3.6 V	3.60	0		±10	μΑ
l <sub>OFF</sub>	Leakage Current	$B_n$ , $V_I$ or $V_O=0$ V to 3.6 V	0	3.60		±10	
	3-State Output	$A_n$ , $B_n$ , $/OE=V_{IH}$	3.60	3.60		±10	μΑ
loz	Leakage $(0 \le V_0 \le 3.6 \text{ V},$	B <sub>n</sub> , /OE= Don't Care <sup>(7)</sup>	3.60	0		±10	
	V <sub>I</sub> =V <sub>IH</sub> or V <sub>IL</sub> )	A <sub>n</sub> , /OE= Don't Care <sup>(7)</sup>	0	3.60		±10	
I <sub>CCA/B</sub>		V <sub>I</sub> =V <sub>CCI</sub> or GND; I <sub>O</sub> =0	1.10 to 3.60	1.10 to 3.60		20	μΑ
I <sub>CCZ</sub>		VI=VCCI OI GIND, IO=0	1.10 to 3.60	1.10 to 3.60		20	
l	Quiescent	V <sub>I</sub> =V <sub>CCA</sub> or GND; I <sub>O</sub> =0	1.10 to 3.60	0		-10	
I <sub>CCA</sub>	Supply Current <sup>(8)</sup>	VI=VCCA OF GIND, IO=0	0	1.10 to 3.60		10	
1//		V. V or CND: I- O	0	1.10 to 3.60		-10	
I <sub>CCB</sub>	/	$V_{I}=V_{CCB}$ or GND; $I_{O}=0$	1.10 to 3.60	0	1	10	
ΔI <sub>CCA/B</sub>	Increase in I <sub>CC</sub> per Input; Other Inputs at V <sub>CC</sub> or GND	V <sub>IH</sub> =3.0 V	3.60	3.60		500	μА

## Notes:

- $$\begin{split} V_{\text{CCI}} &= \text{the } V_{\text{CC}} \text{ associated with the data input under test.} \\ V_{\text{CCO}} &= \text{the } V_{\text{CC}} \text{ associated with the output under test.} \end{split}$$
- Don't care = any valid logic level.
- Reflects current per supply, V<sub>CCA</sub> or V<sub>CCB</sub>.

## **AC Electrical Characteristics**

		T <sub>A</sub> = -40 to +85°C										
Symbol	Parameter		=3.0 V 3.6 V		=2.3 V 2.7 V		1.65 V .95 V		=1.4 V  .6 V		=1.1 V I.3V	Unit
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
V <sub>CCA</sub> =3.0	V to 3.6 V											
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay A to B	0.2	3.5	0.3	3.9	0.5	5.4	0.6	6.8	1.4	22.0	ns
IPLH, IPHL	Propagation Delay B to A	0.2	3.5	0.2	3.8	0.3	4.0	0.5	4.3	0.8	13.0	115
t <sub>PZH,</sub> t <sub>PZL</sub>	Output Enable /OE to B	0.5	4.0	0.7	4.4	1.0	5.9	1.0	6.4	1.5	17.0	ns
IPZH, IPZL	Output Enable /OE to A	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	115
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Output Disable /OE to B	0.2	3.8	0.2	4.0	0.7	4.8	1.5	6.2	2.0	17.0	ns
IPHZ, IPLZ	Output Disable /OE to A	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	115
V <sub>CCA</sub> =2.3	V to 2.7 V											
	Propagation Delay A to B	0.2	3.8	0.4	4.2	0.5	5.6	0.8	6.9	1.4	22.0	
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay B to A	0.3	3.9	0.4	4.2	0.5	4.5	0.5	4.8	1.0	7.0	ns
	Output Enable /OE to B	0.6	4.2	0.8	4.6	1.0	6.0	1.0	6.8	1.5	17.0	
t <sub>PZH</sub> , t <sub>PZL</sub>	Output Enable /OE to A	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	ns
	Output Disable /OE to B	0.2	4.1	0.2	4.3	0.7	4.8	1.5	6.7	2.0	17.0	
$t_{PHZ,} t_{PLZ}$	Output Disable /OE to A	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	ns
V <sub>CCA</sub> =1.6	5 V to 1.95 V								/			
	Propagation Delay A to B	0.3	4.0	0.5	4.5	0.8	5.7	0.9	7.1	1.5	22.0	
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay B to A	0.5	5.4	0.5	5.6	0.8	5.7	1.0	6.0	1.2	8.0	ns
	Output Enable /OE to B	0.6	5.2	0.8	5.4	1.2	6.9	1.2	7.2	1.5	18.0	
t <sub>PZH,</sub> t <sub>PZL</sub>	Output Enable /OE to A	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	ns
	Output Disable /OE to B	0.2	5.1	0.2	5.2	0.8	5.2	1.5	7.0	2.0	17.0	
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Output Disable /OE to A	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	- ns

Continued on the following page...

## **AC Electrical Characteristics**

						T <sub>A</sub> = -40	to +85°C	;				
Symbol	Parameter		=3.0 V 3.6 V		=2.3 V 2.7 V		1.65 V .95 V		=1.4 V  .6 V		=1.1 V 1.3V	Unit
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
V <sub>CCA</sub> =1.4	V to 1.6 V			- 74								
t <sub>PLH,</sub> t <sub>PHL</sub>	Propagation Delay A to B	0.5	4.3	0.5	4.8	1.0	6.0	1.0	7.3	1.5	22.0	- ns
IPLH, IPHL	Propagation Delay B to A	0.6	6.8	0.8	6.9	0.9	7.1	1.0	7.3	1.3	9.5	115
tt_	Output Enable /OE to B	1.1	7.5	1.1	7.6	1.3	7.7	1.4	7.9	2.0	20.0	- ns
t <sub>PZH,</sub> t <sub>PZL</sub>	Output Enable /OE to A	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	115
tphz. tplz	Output Disable /OE to B	0.4	6.1	0.4	6.2	0.9	6.2	1.5	7.5	2.0	18.0	20
IPHZ, IPLZ	Output Disable /OE to A	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	ns
V <sub>CCA</sub> =1.1	V to 1.3 V								V <sub>C</sub>			
	Propagation Delay A to B	0.8	13.0	1.0	7.0	1.2	8.0	1.3	9.5	2.0	24.0	20
t <sub>PLH,</sub> t <sub>PHL</sub>	Propagation Delay B to A	1.4	22.0	1.4	22.0	1.5	22.0	1.5	22.0	2.0	24.0	ns
t t	Output Enable /OE to B	1.0	12.0	1.0	9.0	2.0	10.0	2.0	11.0	2.0	24.0	no
t <sub>PZH</sub> , t <sub>PZL</sub>	Output Enable /OE to A	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	ns
t t	Output Disable /OE to B	1.0	15.0	0.7	7.0	1.0	8.0	2.0	10.0	2.0	20.0	ne
t <sub>PHZ,</sub> t <sub>PLZ</sub>	Output Disable /OE to A	2.0	15.0	2.0	12.0	2.0	12.0	2.0	12.0	2.0	12.0	ns

## Capacitance

Symbol	Parameter	Conditions	T <sub>A</sub> =+25°C		
Symbol	Farameter	Conditions	Typical	Unit	
C <sub>IN</sub>	Input Capacitance (Pins O/E, TR)	$V_{\text{CCA}} = V_{\text{CCB}} = 3.3 \text{ V}, V_{\text{I}} = 0 \text{V or } V_{\text{CCA/B}}$	4	pF	
C <sub>I/O</sub>	Input / Output Capacitance A <sub>n</sub> , B <sub>n</sub> Ports	$V_{\text{CCA}} = V_{\text{CCB}} = 3.3 \text{ V}, V_{\text{I}} = 0 \text{V or } V_{\text{CCA/B}}$	5	pF	
$C_{PD}$	Power Dissipation Capacitance	$V_{CCA}=V_{CCB}=3.3 \text{ V}, V_{I}=0\text{V or } V_{CC}, f=10 \text{ MHz}$	20	pF	

## **AC Loadings and Waveforms**

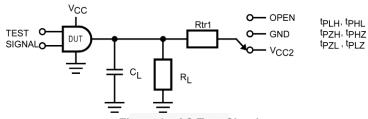
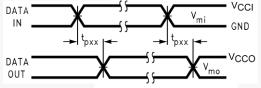


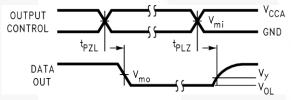
Figure 2. AC Test Circuit

Test	Switch
t <sub>PLH</sub> ,t <sub>PHL</sub>	Open
t <sub>PLZ</sub> ,t <sub>PZL</sub>	$V_{CC0}$ • 2 at $V_{CC0}$ =3.3 ±0.3 V, 2.5 V ±0.2 V, 1.8 V ±0.15 V, 1.5 V ±0.1 V, 1.2 V ±0.1 V
t <sub>PHZ</sub> ,t <sub>PZH</sub>	GND

Table 1. AC Load Table

: abio :: /to =oaa :abio			
V <sub>cco</sub>	C <sub>L</sub>	RL	Rtr1
1.2 V ±0.1 V	15 pF	2 kΩ	2 kΩ
1.5 V ±0.1 V	15 pF	2 kΩ	2 kΩ
1.8 V ±0.15 V	15 pF	2 kΩ	2 kΩ
2.5 V ±0.2 V	15 pF	2 kΩ	2 kΩ
3.3 V ±0.3 V	15 pF	2 kΩ	2 kΩ





#### Note:

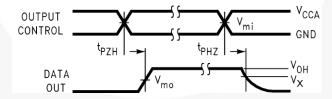
- 9. Input  $t_R=t_F=2.0$  ns, 10% to 90%.
- 10. Input  $t_{\text{R}}\text{-}t_{\text{F}}\text{=}2.5$  ns, 10% to 90%, at  $V_{\text{I}}\text{=}3.0$  V to 3.6 V only.

Figure 3. Waveform for Inverting and Non-Inverting Functions

#### Note:

- 11. Input  $t_R=t_F=2.0$  ns, 10% to 90%.
- 12. Input  $t_R$ - $t_F$ =2.5 ns, 10% to 90%, at  $V_I$ =3.0 V to 3.6 V only.

Figure 4. 3-State Output Low Enable and Disable for Low Voltage Logic



#### Notes:

- 13. Input  $t_R=t_F=2.0$  ns, 10% to 90%.
- 14. Input  $t_R$ - $t_F$ =2.5 ns, 10% to 90%, at  $V_I$ =3.0 V to 3.6 V only.

Figure 5. 3-State Output High Enable and Disable for Low Voltage Logic

Symbol	V <sub>CC</sub>				
	3.3 V ± 0.3 V	2.5 V ± 0.2 V	1.8 V ± 0.15 V	1.5 V ± 0.1 V	1.2 V ± 0.1 V
V <sub>MI</sub>	V <sub>CCI</sub> /2	V <sub>CCI</sub> /2	V <sub>CCI</sub> /2	V <sub>CCI</sub> /2	V <sub>CCI</sub> /2
$V_{MO}$	V <sub>CCO</sub> /2	V <sub>CCO</sub> /2	V <sub>CCO</sub> /2	V <sub>CCO</sub> /2	V <sub>CCO</sub> /2
V <sub>X</sub>	V <sub>OH</sub> - 0.3 V	V <sub>OH</sub> – 0.15 V	V <sub>OH</sub> – 0.15 V	V <sub>OH</sub> – 0.1 V	V <sub>OH</sub> – 0.1 V
V <sub>Y</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OL</sub> + 0.15 V	V <sub>OL</sub> + 0.15 V	V <sub>OL</sub> + 0.1 V	V <sub>OL</sub> + 0.1 V

#### Note:

15. For  $V_{MI}$   $V_{CCO} = V_{CCA}$  for control pins  $T/\overline{R}$  and  $\overline{OE}$  or  $V_{CCA}/2$ .

## **Physical Dimensions**

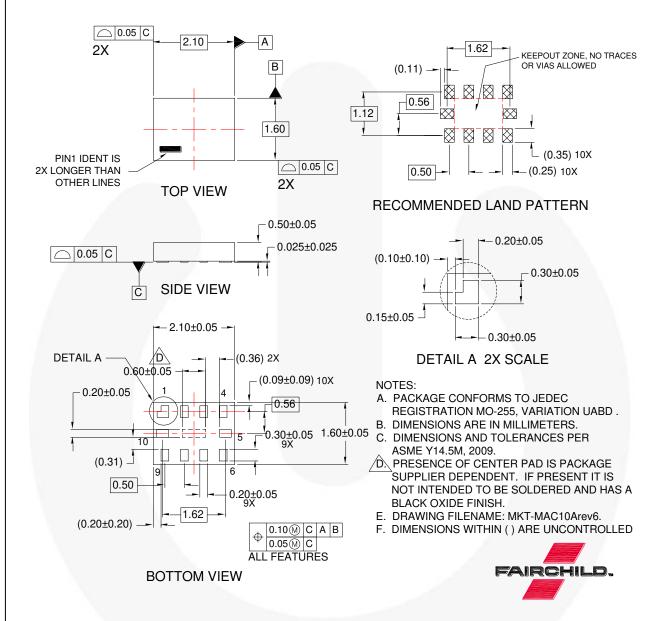


Figure 6. 10-Lead, MicroPak™, JEDEC MO255,1.6 x 2.1 mm

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